SQM40022EM

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FREE

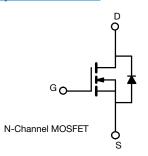
Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY				
V _{DS} (V)	40			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.00163			
I _D (A)	150			
Configuration	Single			
Package	TO-263-7L			

FEATURES

- TrenchFET® power MOSFET
- · Package with low thermal resistance
- 100 % $R_{\rm q}$ and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	40		
Gate-source voltage		V _{GS}	± 20	- V	
Continuous drain current	$T_C = 25 \ ^\circ C \ ^a$	1	150		
	T _C = 125 °C	- I _D	125		
Continuous source current (diode conductio	I _S	136	А		
Pulsed drain current ^b	I _{DM}	300			
Single pulse avalanche current	L = 0.1 mH	I _{AS}	60		
Single pulse avalanche energy	L = 0.1 IIIH	E _{AS}	180	mJ	
Maximum power dissipation ^b	T _C = 25 °C	PD	150	W	
	T _C = 125 °C		50	vv	
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS						
PARAMETER		SYMBOL	LIMIT	UNIT		
Junction-to-ambient	PCB mount ^c	R _{thJA}	40	°C/W		
Junction-to-case (drain)		R _{thJC}	1	C/ VV		

Notes

a. Package limited

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

c. When mounted on 1" square PCB (FR4 material)

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SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$		40	-	-	v
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$		2.5	3.0	3.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	= 0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		V _{GS} = 0 V V _{DS} = 40 V		-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 125 °C	-	-	50	μA
		$V_{GS} = 0 V$	V _{DS} = 40 V, T _J = 175 °C	-	-	300	μA
On-state drain current ^a	I _{D(on)}	$V_{GS} = 10 V$	$V_{DS} \ge 5 V$	100	-	-	Α
		$V_{GS} = 10 V$	I _D = 35 A	-	0.00133	0.00163	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 35 A, T _J = 125 °C	-	-	0.00268	Ω
		V _{GS} = 10 V	I _D = 35 A, T _J = 175 °C	-	-	0.00326	
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 35 A	-	143	-	S
Dynamic ^b		•			•		
Input capacitance	Ciss			-	6783	9200	
Output capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = 25 V, f = 1 MHz	-	1771	2400	pF
Reverse transfer capacitance	C _{rss}			-	109	150	
Total gate charge ^c	Qg			-	106	160	
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 \text{ V}, I_{D} = 100 \text{ A}$	-	33	-	nC
Gate-drain charge ^c	Q _{gd}			-	21	-	
Gate resistance	Rg	f = 1 MHz		1.25	2.75	4.35	Ω
Turn-on delay time ^c	t _{d(on)}			-	19	30	
Rise time ^c	tr	V _{DD} =	= 20 V, R _L = 0.2 Ω	-	194	300	
Turn-off delay time ^c	t _{d(off)}	I _D ≅ 100 A	, V _{GEN} = 10 V, R _g = 1 Ω	-	45	70	ns
Fall time ^c	t _f			-	26	40	
Source-Drain Diode Ratings and Charac	cteristics ^b				•		
Pulsed current ^a	I _{SM}			-	-	300	Α
Forward voltage	V _{SD}	I _F = 60 A, V _{GS} = 0 V		-	0.83	1.5	V
Body diode reverse recovery time	t _{rr}	I _F = 30 A, di/dt = 100 A/μs		-	88	180	ns
Body diode reverse recovery charge	Q _{rr}			-	186	380	nC
Reverse recovery fall time	t _a			-	57	-	
Reverse recovery rise time	t _b			-	31	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}	1		-	-4.6	-	Α

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

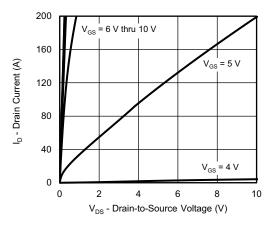
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

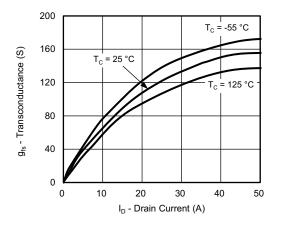
2



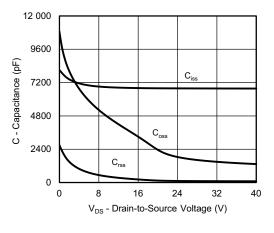
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



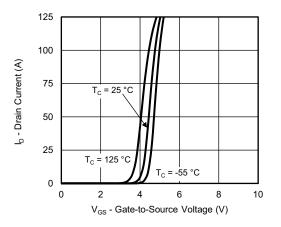
Output Characteristics



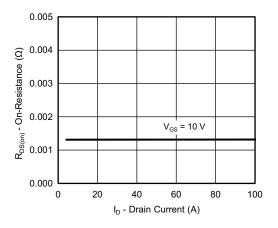
Transconductance



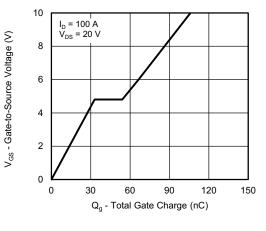
Capacitance



Transfer Characteristics



On-Resistance vs. Drain Current



Gate Charge

S18-0116-Rev. A, 29-Jan-18

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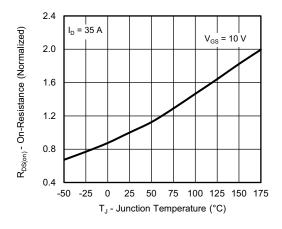
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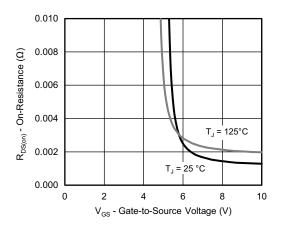
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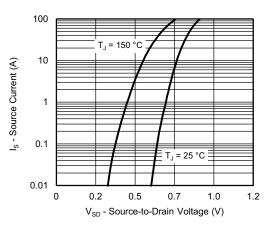
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



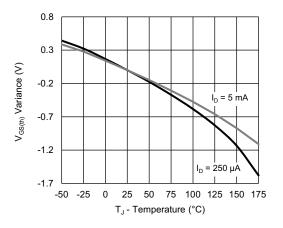
On-Resistance vs. Junction Temperature



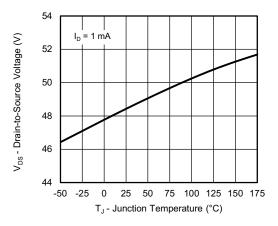
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage







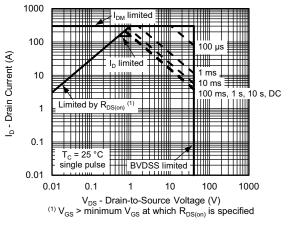
Drain Source Breakdown vs. Junction Temperature

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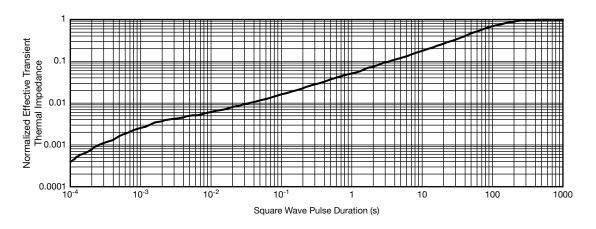
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

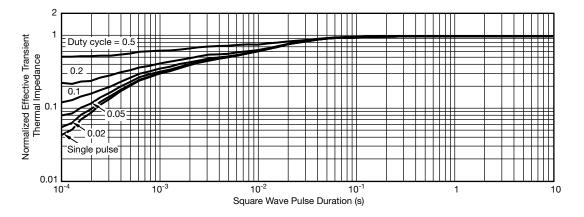


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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

S18-0116-Rev. A, 29-Jan-18

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

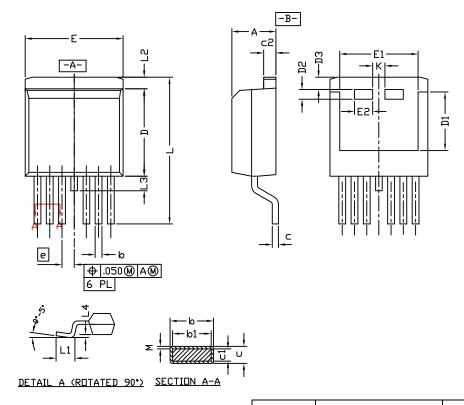
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77695.

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D²PAK (TO-263-7L) Case Outline



Notes

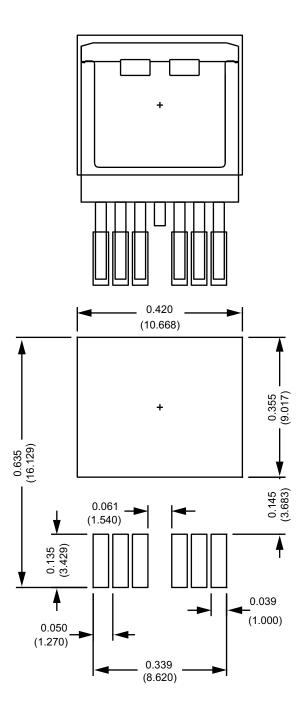
- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin to pin coplanarity max. 4 mils.
- 4. Lead thickness 25 mils.
- 5. For SUM part numbers lead thickness is 24 mils to 29 mils.
- 6. For reference only.
- 7. Use inches as the primary measurement.
- 8. This feature is only for SUM.

	INCHES		MILLIMETERS		
DIM.	MIN.	MAX.	MIN.	MAX.	
Α	0.160	0.190	4.064	4.826	
b	0.020	0.039	0.508	0.990	
b1	0.020	0.035	0.508	0.889	
b2	0.045	0.055	1.143	1.397	
c* SUB	0.012	0.018	0.305	0.457	
c* SUM	0.022	0.028	0.559	0.711	
c1	0.018	0.025	0.457	0.635	
c2	0.045	0.055	1.143	1.397	
D	0.340	0.380	8.636	9.652	
D1	0.220	0.240	5.588	6.096	
D2	0.038	0.042	0.965	1.067	
D3	0.045	0.055	1.143	1.397	
E	0.380	0.410	9.652	10.414	
E1	0.245	-	6.223	-	
E2	0.072	0.078	1.829	1.981	
е	0.050	BSC	1.27 BSC		
K	0.045	0.055	1.143	1.397	
L	0.575	0.625	14.605	15.875	
L1	0.090	0.110	2.286	2.794	
L2	0.040	0.055	1.016	1.397	
L3	0.050	0.070	1.270	1.778	
L4	0.010 BSC		0.254 BSC		
М	-	0.002	-	0.050	
ECN: T13-0709-Rev. B, 30-Sep-13 DWG: 6006					





Recommended Land Pattern D²PAK (TO-263-7L)



Revision: 23-Jul-2020



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